1.8-V, 7-MHz, 90-dB CMRR, SINGLE-SUPPLY, RAIL-TO-RAIL I/O OPERATIONAL AMPLIFIER

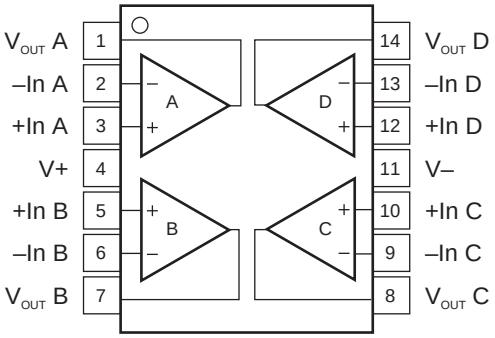
FEATURES

- **Qualified for Automotive Applications**
- **1.8-V Operation**
- **Bandwidth: 7 MHz**
- **CMRR: 90 dB (Typ)**
- **Slew Rate: 5 V/μs**
- **Low Offset: 500 μV (Max)**
- **Quiescent Current: 750 μA/Channel (Max)**
- **Shutdown Mode: <1 μA/Channel**

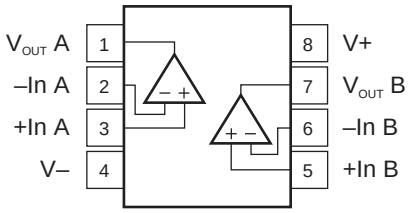
APPLICATIONS

- **Signal Conditioning**
- **Data Acquisition**
- **Process Control**
- **Active Filters**
- **Test Equipment**

OPA4364...D PACKAGE
(TOP VIEW)



OPA2364...D PACKAGE
(TOP VIEW)



DESCRIPTION

The OPA2364 and OPA4364 are high-performance CMOS operational amplifiers optimized for low-voltage single-supply operation. These miniature low-cost amplifiers are designed to operate on single supplies from 1.8 V (±0.9 V) to 5.5 V (±2.75 V). Applications include sensor amplification and signal conditioning in battery-powered systems.

The OPAx364 family offers excellent CMRR without the crossover associated with traditional complimentary input stages. This results in excellent performance for driving analog-to-digital (A/D) converters without degradation of differential linearity and total harmonic distortion (THD). The input common-mode range includes both the negative and positive supplies. The output voltage swing is within 10 mV of the rails.

The dual version is available in an SO-8 package and the quad package is available in an SO-14 package. All versions are specified for operation from –40°C to 125°C.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of the Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

Copyright © 2006, Texas Instruments Incorporated



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ORDERING INFORMATION

PRODUCT	PACKAGE LEAD	PACKAGE DESIGNATOR	T_A	PACKAGE MARKING	ORDERING NUMBER	TRANSPORT MEDIA, QUANTITY
OPA2364AQDRQ1	SO-8	D	–40°C to 125°C	OP2364	OPA2364AQDRQ1	Tape and reel, 2500
OPA4364AQDRQ1	SO-14	D	–40°C to 125°C	OPA4364AQ	OPA4364AQDRQ1	Tape and reel, 2500

ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
	Supply voltage			5.5	V
	Signal input terminals	Voltage range(2)	–0.5	(V+) + 0.5	V
		Current(2)		±10	mA
	Enable input range		(V–) –0.5	5.5	V
	Output short circuit(3)			Continuous	
	Operating temperature range		–40	150	°C
T_{stg}	Storage temperature range		–65	150	°C
T_J	Junction temperature			150	°C
	Lead temperature (soldering, 10 s)			300	°C

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.
(2) Input terminals are diode clamped to the power-supply rails. Input signals that can swing more than 0.5 V beyond the supply rails should be current limited to 10 mA or less.
(3) Short circuit to ground one amplifier per package

ELECTRICAL CHARACTERISTICS: V_S = 1.8 V to 5.5 V

Boldface limits apply over the specified temperature range, **T_A = –40°C to 125°C**, T_A = 25°C, R_L = 10 kΩ connected to V_S/2, and V_{OUT} = V_S/2, V_{CM} = V_S/2 (unless otherwise noted)

PARAMETER			TEST CONDITIONS		MIN	TYP	MAX	UNIT
Offset Voltage								
V_{OS}	Input offset voltage		V_S = 5 V			1	3	mV
dV_{OS}/dT	**Drift**					**3**		**µV/°C**
PSRR	**Power-supply rejection ratio**		**V_S = 1.8 V to 5.5 V, V_{CM} = 0**			**80**	**330**	**µV/V**
	Channel separation, dc					1		µV/V
Input Bias Current								
I_B	Input bias current					±1	±10	pA
			Over temperature		See Typical Characteristics			
I_{OS}	Input offset current					±1	±10	pA
Noise								
e_n	Input voltage noise		f = 0.1 Hz to 10 Hz			10		$µV_{P-P}$
	Input voltage noise density		f = 10 kHz			17		nV/√Hz
i_n	Input current noise density		f = 10 kHz			0.6		fA/√Hz
Input Voltage Range								
V_{CM}	Common-mode voltage range				(V–) – 0.1		(V+) + 0.1	V
CMRR	**Common-mode rejection ratio**		**(V–) – 0.1 V < V_{CM} < (V+) + 0.1 V**		**74**	**90**		**dB**
Input Capacitance								
	Differential					2		pF
	Common mode					3		pF
Open-Loop Gain								
A_{OL}	Open-loop voltage gain		R_L = 10 kΩ, 100 mV < V_O < (V+) – 100 mV		94	100		dB
			OPA4364A		90			
			Over temperature, V_S = 1.8 V to 5.5 V		**86**			**dB**
Frequency Response								
GBW	Gain bandwidth product		C_L = 100 pF			7		MHz
SR	Slew rate		C_L = 100 pF, G = 1			5		V/µs
t_s	Settling time	0.1%	C_L = 100 pF, V_S = 5 V, 4-V step, G = 1			1		µs
		0.01%	C_L = 100 pF, V_S = 5 V, 4-V step, G = 1			1.5		µs
	Overload recovery time		C_L = 100 pF, V_{IN} × Gain > V_S			0.8		µs
THD+N	Total harmonic distortion + noise		C_L = 100 pF, V_S = 5 V, G = 1, f = 20 Hz to 20 kHz			0.002%		
Output								
	Voltage output swing	From rail	R_L = 10 kΩ			10	20	mV
		Over temperature	**R_L = 10 kΩ**	**V_{OL}**			**20**	**mV**
				V_{OH}			**40**	
I_{SC}	Short-circuit current				See Typical Characteristics			
C_{LOAD}	Capacitive load drive				See Typical Characteristics			
Power Supply								
V_S	Specified voltage				1.8		5.5	V
	Operating voltage					1.8 to 5.5		V
I_Q	**Quiescent current (per amplifier)**		**V_S = 1.8 V**			**650**	**750**	**µA**
			V_S = 3.6 V			**850**	**1000**	**µA**
			V_S = 5.5 V			**1.1**	**1.4**	**mA**

ELECTRICAL CHARACTERISTICS: V_S = 1.8 V to 5.5 V (continued)

Boldface limits apply over the specified temperature range, **T_A = –40°C to 125°C**, T_A = 25°C, R_L = 10 kΩ connected to V_S/2, and V_{OUT} = V_S/2, V_{CM} = V_S/2 (unless otherwise noted)

PARAMETER			TEST CONDITIONS	MIN	TYP	MAX	UNIT
Temperature Range							
	Specified range			–40		125	°C
	Storage range			–65		150	°C
θ_{JA}	Thermal resistance	SO-8			150		°C/W
		SO-14			100		

TYPICAL CHARACTERISTICS

At T_{CASE} = 25°C, R_L = 10 kΩ, and connected to $V_S/2$, $V_{OUT} = V_S/2$, $V_{CM} = V_S/2$ (unless otherwise noted)

OPEN-LOOP GAIN/PHASE vs FREQUENCY

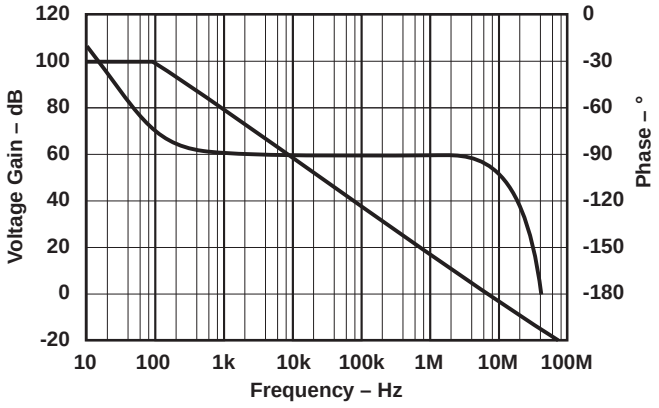


Figure 1.

COMMON-MODE REJECTION RATIO vs FREQUENCY

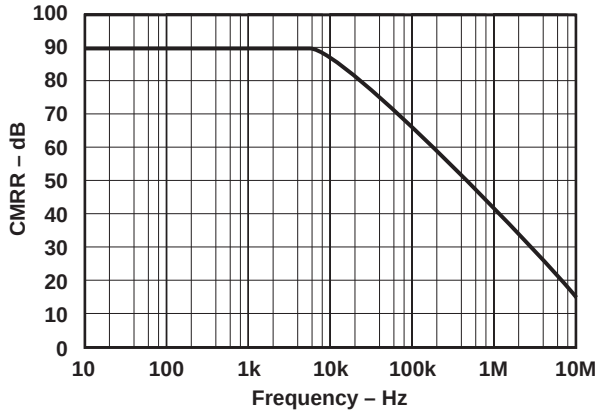


Figure 2.

POWER-SUPPLY REJECTION RATIO vs FREQUENCY

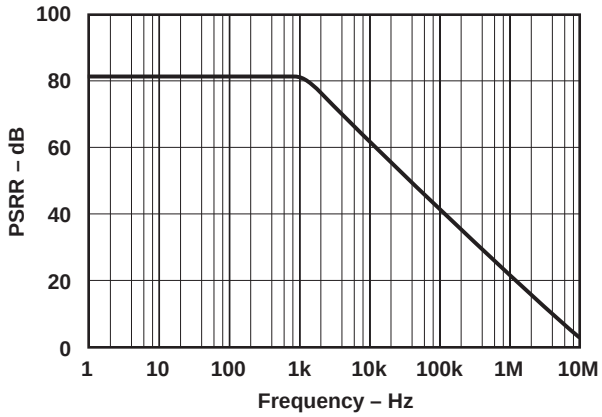


Figure 3.

QUIESCENT CURRENT vs SUPPLY VOLTAGE

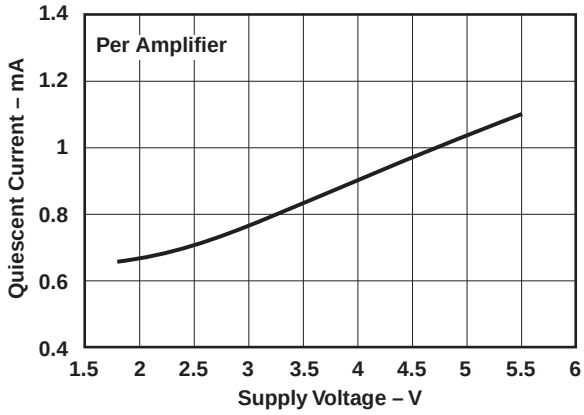


Figure 4.

TYPICAL CHARACTERISTICS (continued)

At T_{CASE} = 25°C, R_L = 10 kΩ, and connected to V_S/2, V_{OUT} = V_S/2, V_{CM} = V_S/2 (unless otherwise noted)

TOTAL HARMONIC DISTORTION + NOISE vs FREQUENCY

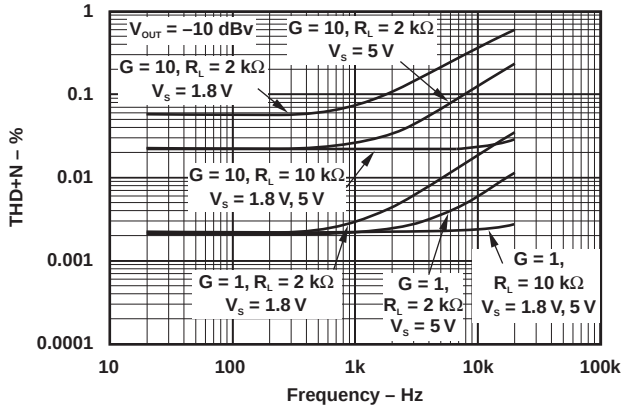


Figure 5.

TOTAL HARMONIC DISTORTION + NOISE vs FREQUENCY

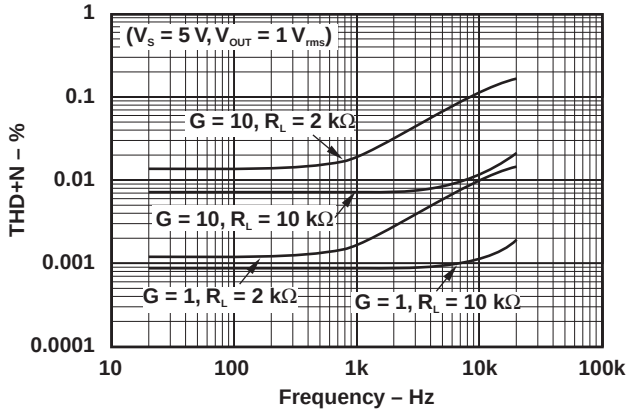


Figure 6.

INPUT VOLTAGE NOISE SPECTRAL DENSITY vs FREQUENCY

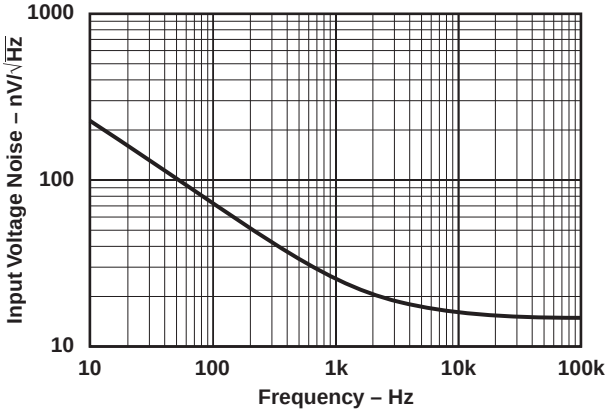


Figure 7.

SHORT-CIRCUIT CURRENT vs SUPPLY VOLTAGE

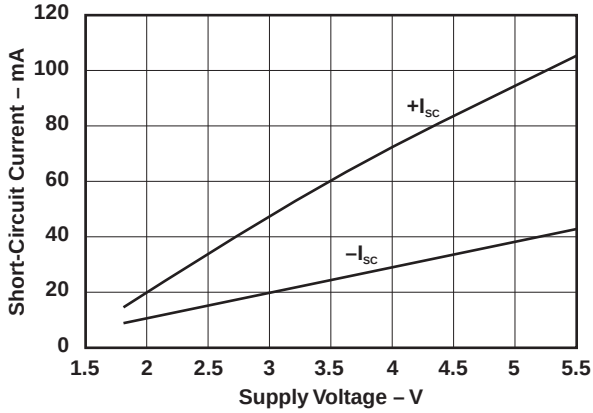


Figure 8.

TYPICAL CHARACTERISTICS (continued)

At T_{CASE} = 25°C, R_L = 10 kΩ, and connected to $V_S/2$, $V_{OUT} = V_S/2$, $V_{CM} = V_S/2$ (unless otherwise noted)

OUTPUT VOLTAGE SWING vs OUTPUT CURRENT

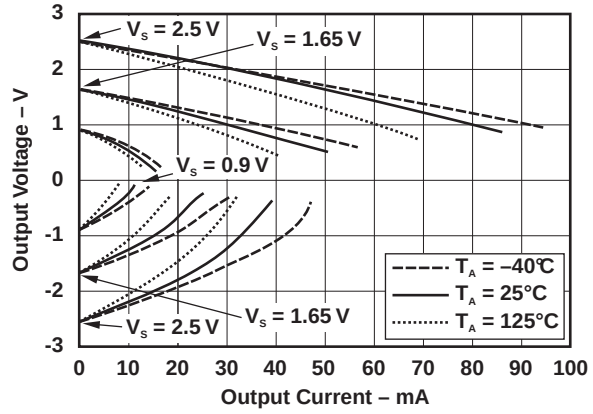


Figure 9.

INPUT BIAS CURRENT vs INPUT COMMON-MODE VOLTAGE

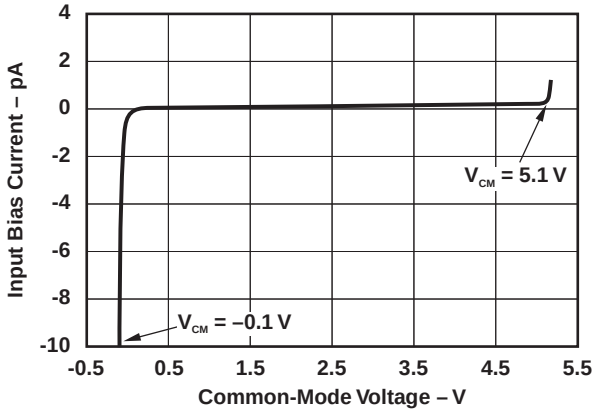


Figure 10.

INPUT OFFSET CURRENT vs TEMPERATURE

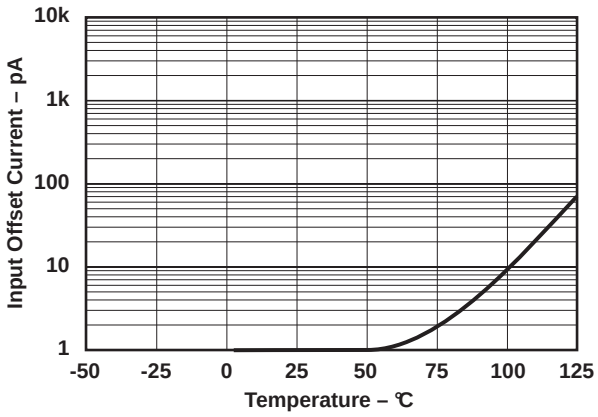


Figure 11.

INPUT BIAS CURRENT vs TEMPERATURE

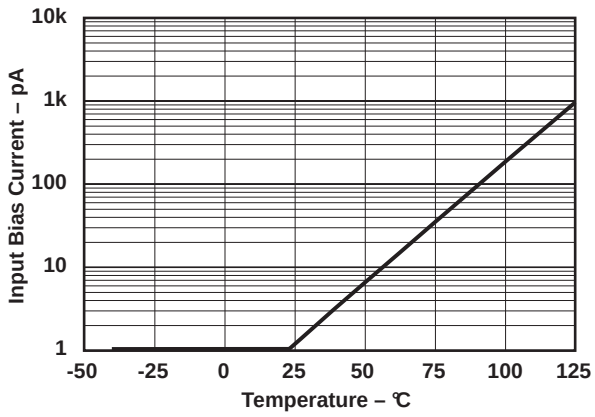


Figure 12.

TYPICAL CHARACTERISTICS (continued)

At T_{CASE} = 25°C, R_L = 10 kΩ, and connected to $V_S/2$, $V_{OUT} = V_S/2$, $V_{CM} = V_S/2$ (unless otherwise noted)

SMALL-SIGNAL OVERSHOOT vs LOAD CAPACITANCE

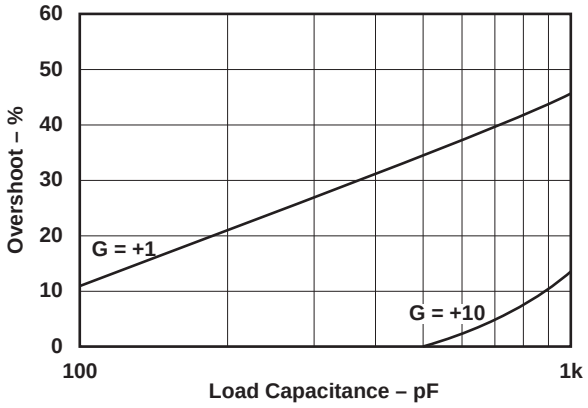


Figure 13.

SETTLING TIME vs CLOSED-LOOP GAIN

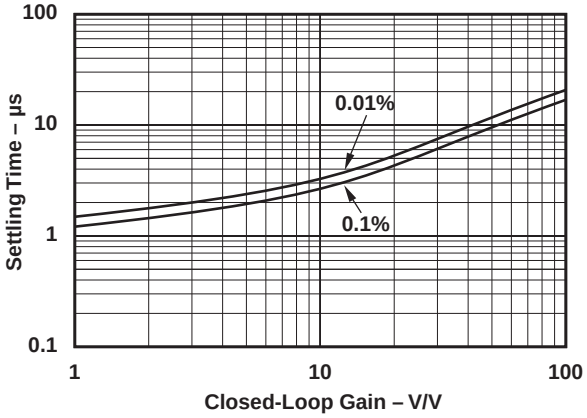


Figure 14.

OFFSET DRIFT DISTRIBUTION

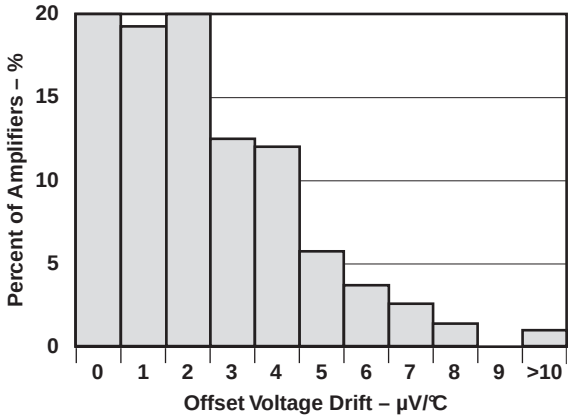


Figure 15.

OUTPUT ENABLE CHARACTERISTIC (V_S = 5 V, V_{OUT} = 20 kHz Sinusoid)

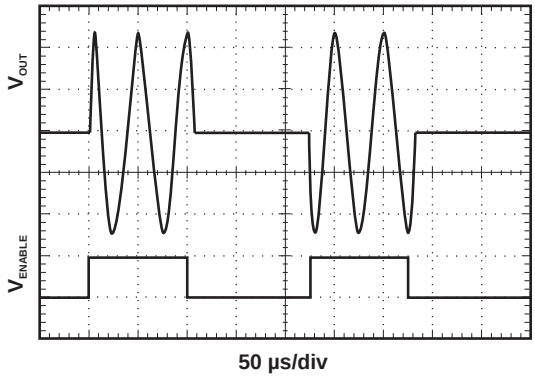


Figure 16.

TYPICAL CHARACTERISTICS (continued)

At T_{CASE} = 25°C, R_L = 10 kΩ, and connected to $V_S/2$, $V_{OUT} = V_S/2$, $V_{CM} = V_S/2$ (unless otherwise noted)

CHANNEL SEPARATION vs FREQUENCY

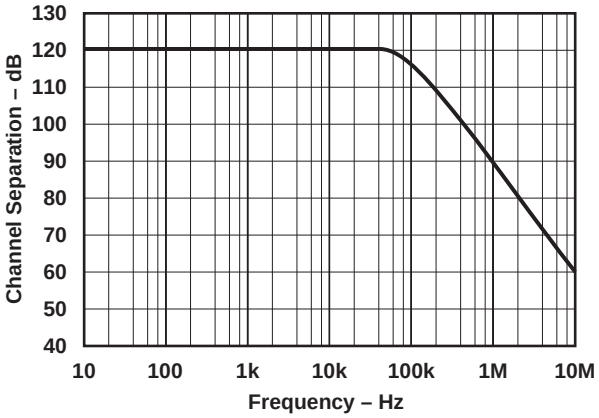


Figure 17.

SMALL-SIGNAL STEP RESPONSE (C_L = 100 pF)

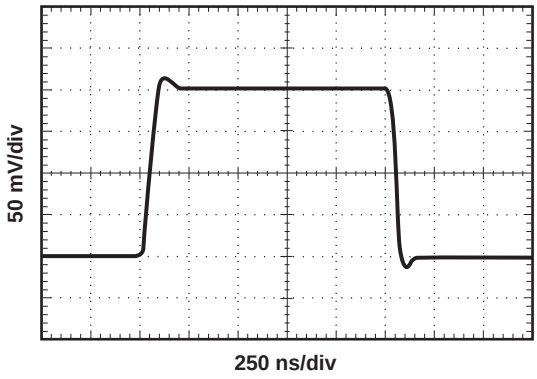


Figure 18.

LARGE-SIGNAL STEP RESPONSE (C_L = 100 pF)

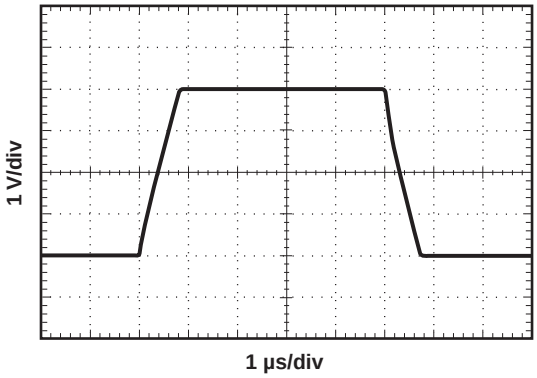


Figure 19.

APPLICATION INFORMATION

The OPAx364 series op amps are rail-to-rail operational amplifiers with excellent CMRR, low noise, low offset, and wide bandwidth on supply voltages as low as ±0.9 V. This family does not exhibit phase reversal and is unity-gain stable. Specified over the industrial temperature range of –40°C to 125°C, the OPAx364 family offers precision performance for a wide range of applications.

Rail-to-Rail Input

The OPAx364 features excellent rail-to-rail operation, with supply voltages as low as ±0.9 V. The input common-mode voltage range of the OPAx364 family extends 100 mV beyond supply rails. The unique input topology of the OPAx364 eliminates the input offset transition region typical of most rail-to-rail complimentary stage operational amplifiers, allowing the OPAx364 to provide superior common-mode performance over the entire common-mode input range (see Figure 20). This feature prevents degradation of the differential linearity error and THD when driving A/D converters. A simplified schematic of the OPAx364 is shown in Figure 21.

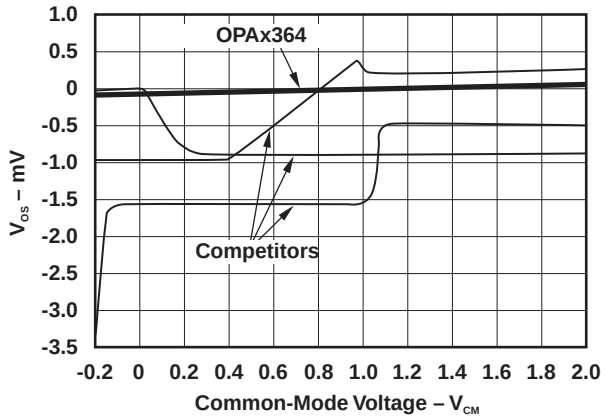


Figure 20. OPAx364 Linear Offset Over Entire Common-Mode Range

APPLICATION INFORMATION (continued)

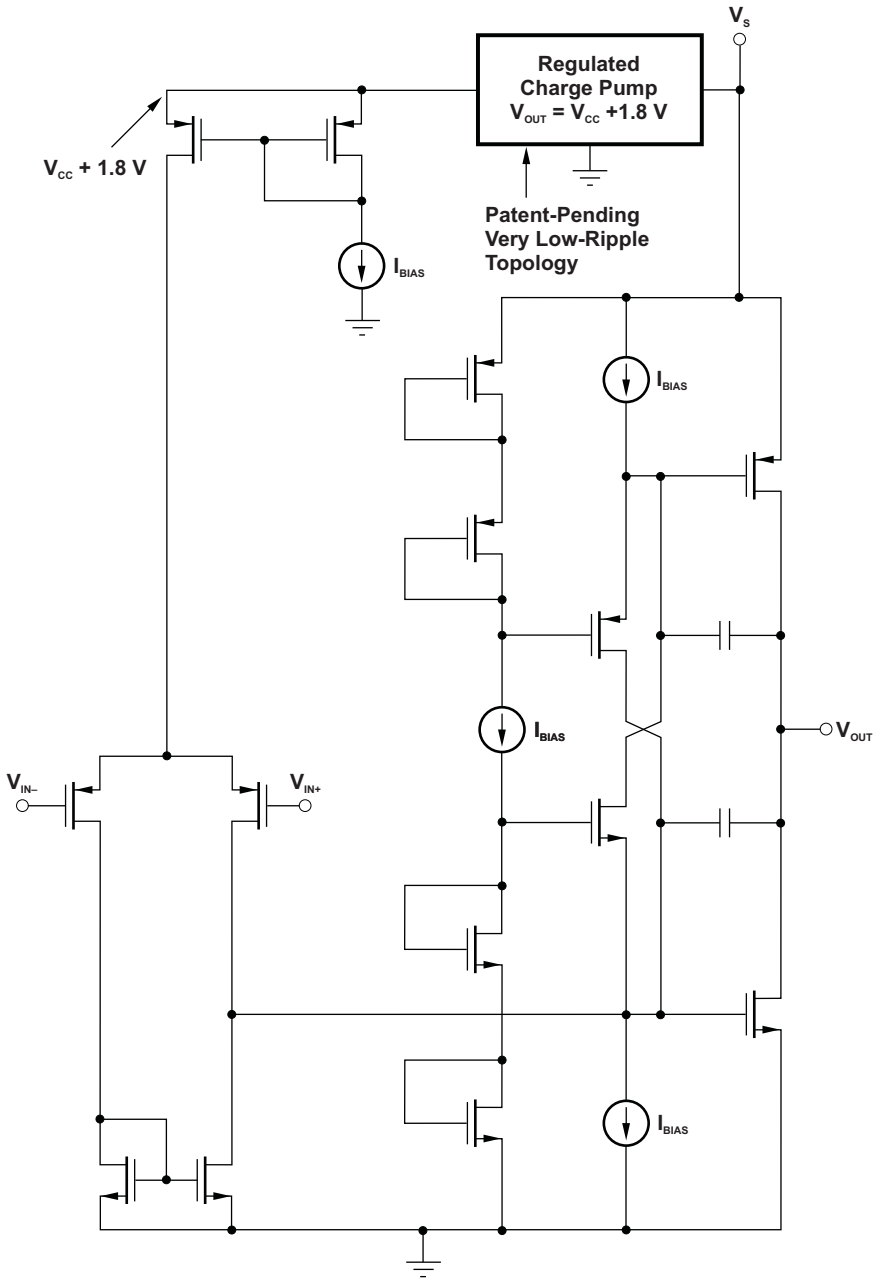


Figure 21. Simplified Schematic

Operating Voltage

The OPAx364 series of operational amplifier parameters are fully specified from 1.8 V to 5.5 V. Single 0.1-µF bypass capacitors should be placed across supply pins and as close to the part as possible. Supply voltages higher than 5.5 V (absolute maximum) may cause permanent damage to the amplifier. Many specifications apply from –40°C to 125°C. Parameters that vary significantly with operating voltages or temperature are shown in the Typical Characteristics.

APPLICATION INFORMATION (continued)

Capacitive Load

The OPAx364 series operational amplifiers can drive a wide range of capacitive loads. However, all operational amplifiers under certain conditions may become unstable. Operational amplifier configuration, gain, and load value are just a few of the factors to consider when determining stability. An operational amplifier in unity-gain configuration is the most susceptible to the effects of capacitive load. The capacitive load reacts with the output resistance of the operational amplifier to create a pole in the small-signal response, which degrades the phase margin.

In unity gain, the OPAx364 series operational amplifiers perform well with a pure capacitive load up to approximately 1000 pF. The equivalent series resistance (ESR) of the loading capacitor may be sufficient to allow the OPAx364 to directly drive large capacitive loads (>1 μF). Increasing gain enhances the amplifier's ability to drive more capacitance as shown in Figure 13.

One method of improving capacitive load drive in the unity gain configuration is to insert a 10-Ω to 20-Ω resistor in series with the output, as shown in Figure 22. This significantly reduces ringing with large capacitive loads. However, if there is a resistive load in parallel with the capacitive load, it creates a voltage divider introducing a dc error at the output and slightly reduces output swing. This error may be insignificant. For instance, with R_L = 10 kΩ and R_S = 20 Ω, there is only about a 0.2% error at the output.

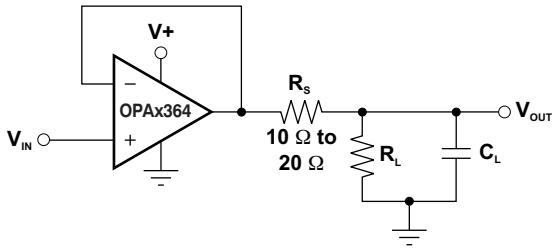


Figure 22. Improving Capacitive Load Drive

Input and ESD Protection

All OPAx364 pins are static protected with internal ESD protection diodes tied to the supplies. These diodes provide overdrive protection if the current is externally limited to 10 mA, as stated in the absolute maximum ratings and shown in Figure 23.

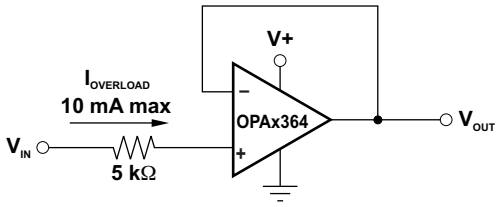


Figure 23. Input Current Protection

Achieving Output Swing to the Operational Amplifier's Negative Rail

Some applications require an accurate output voltage swing from 0 V to a positive full-scale voltage. A good single-supply operational amplifier may be able to swing within a few mV of single supply ground, but as the output is driven toward 0 V, the output stage of the amplifier prevents the output from reaching the negative supply rail of the amplifier.

The output of the OPAx364 can be made to swing to ground, or slightly below, on a single-supply power source. To do so requires use of another resistor and an additional, more-negative power supply than the operational amplifier's negative supply. A pulldown resistor may be connected between the output and the additional negative supply to pull the output down below the value that the output would otherwise achieve as shown in Figure 24.

APPLICATION INFORMATION (continued)

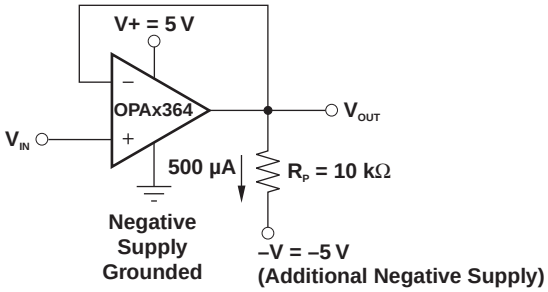


Figure 24. Swing to Ground

This technique does not work with all operational amplifiers. The output stage of the OPAx364 allows the output voltage to be pulled below that of most operational amplifiers, if approximately 500 µA is maintained through the output stage. To calculate the appropriate value load resistor and negative supply, R_L = –V/500 µA. The OPAx364 has been characterized to perform well under the described conditions, maintaining excellent accuracy down to 0 V and as low as –10 mV. Limiting and nonlinearity occurs below –10 mV, with linearity returning as the output is again driven above –10 mV.

Buffered Reference Voltage

Many single-supply applications require a mid-supply reference voltage. The OPAx364 offer excellent capacitive load drive capability and can be configured to provide a 0.9-V reference voltage (see Figure 25). For appropriate loading considerations, see the Capacitive Load section.

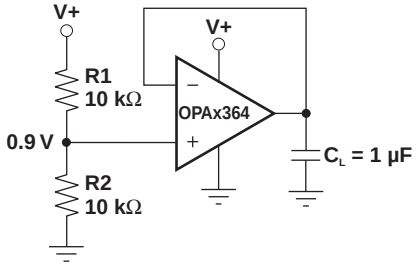


Figure 25. OPAx364 Provides a Stable Reference Voltage

APPLICATION INFORMATION (continued)

Directly Driving the ADS8324 and the MSP430

The OPAx364 series operational amplifiers are optimized for driving medium speed (up to 100 kHz) sampling A/D converters. However, they also offer excellent performance for higher-speed converters. The no crossover input stage of the OPAx364 directly drives A/D converters without degradation of differential linearity and THD. They provide an effective means of buffering the A/D converters input capacitance and resulting charge injection, while providing signal gain. Figure 26 and Figure 27 show the OPAx364 configured to drive the ADS8324 and the 12-bit A/D converter on the MSP430.

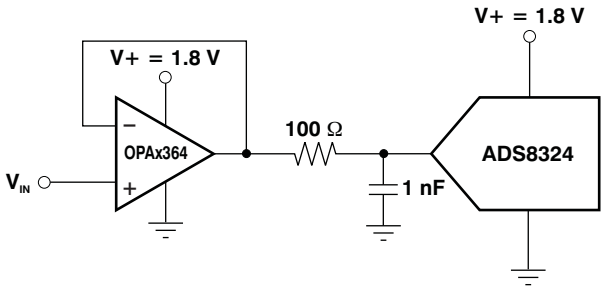


Figure 26. OPAx364 Directly Drives the ADS8324

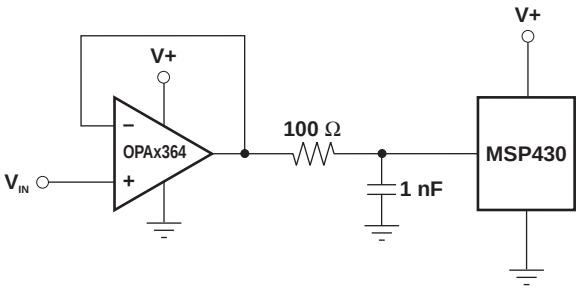


Figure 27. Driving the 12-Bit A/D Converter on the MSP430

Audio Applications

The OPAx364 family has linear offset voltage over the entire input common-mode range. Combined with low-noise, this feature makes the OPAx364 suitable for audio applications. Single-supply 1.8-V operation allows the OPA2364 to be an optimal candidate for dual stereo-headphone drivers and microphone preamplifiers in portable stereo equipment (see Figure 28).

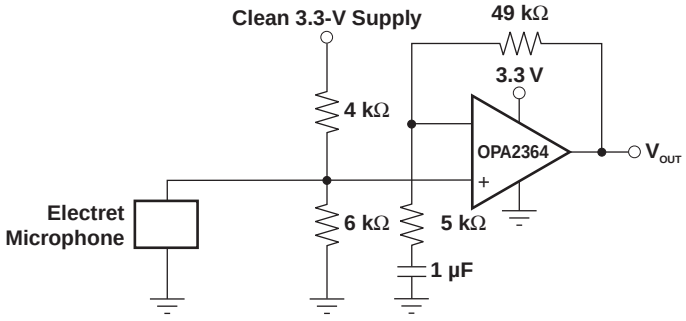


Figure 28. Microphone Preamplifier

APPLICATION INFORMATION (continued)

Active Filtering

Low harmonic distortion and noise specifications plus high gain and slew rate make the OPAx364 optimal candidates for active filtering. Figure 29 shows the implementation of a Sallen-Key, 3-pole, low-pass Bessel filter.

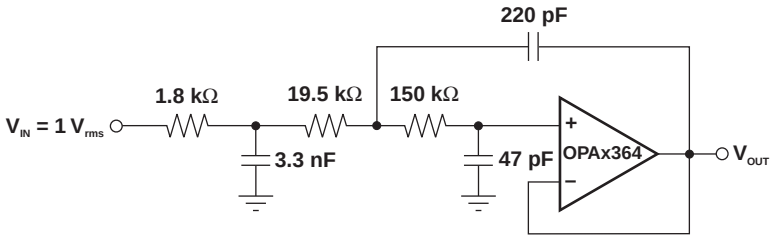


Figure 29. OPAx364 Configured as 3-Pole, 20-kHz, Sallen-Key Filter

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)
OPA4364AQDRQ1	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

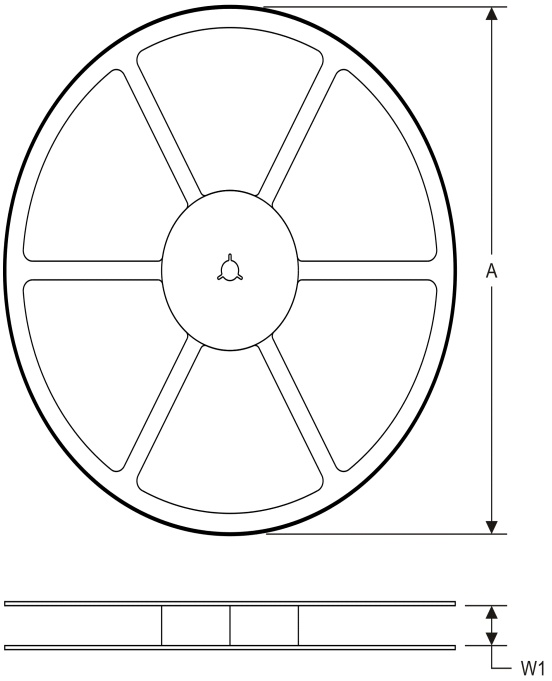
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF OPA4364-Q1 :
- Catalog: OPA4364

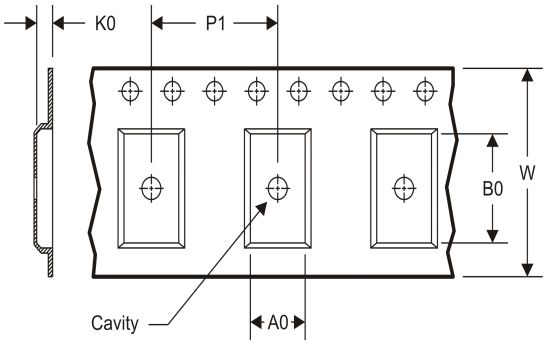
NOTE: Qualified Version Definitions:
- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



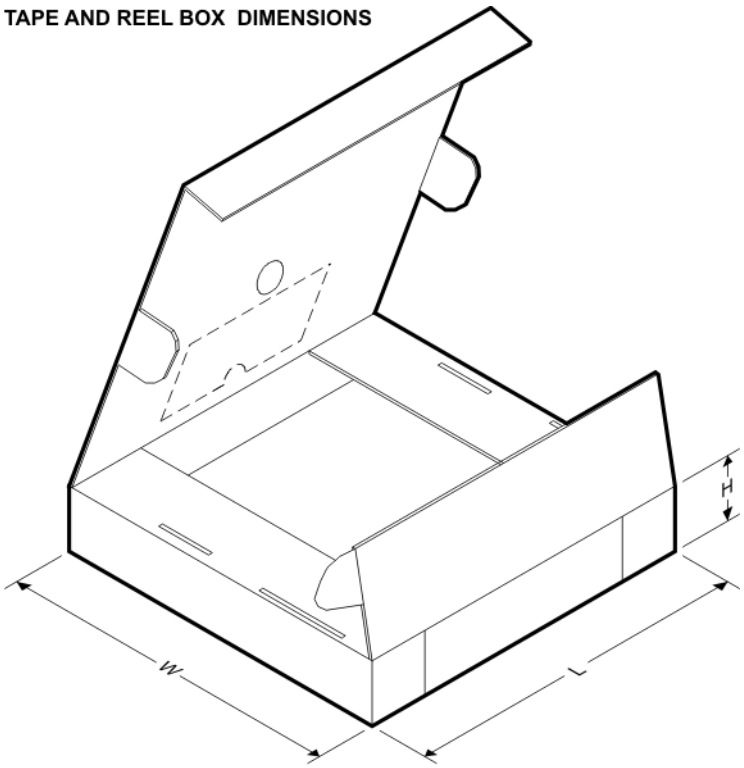
A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OPA4364AQDRQ1	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

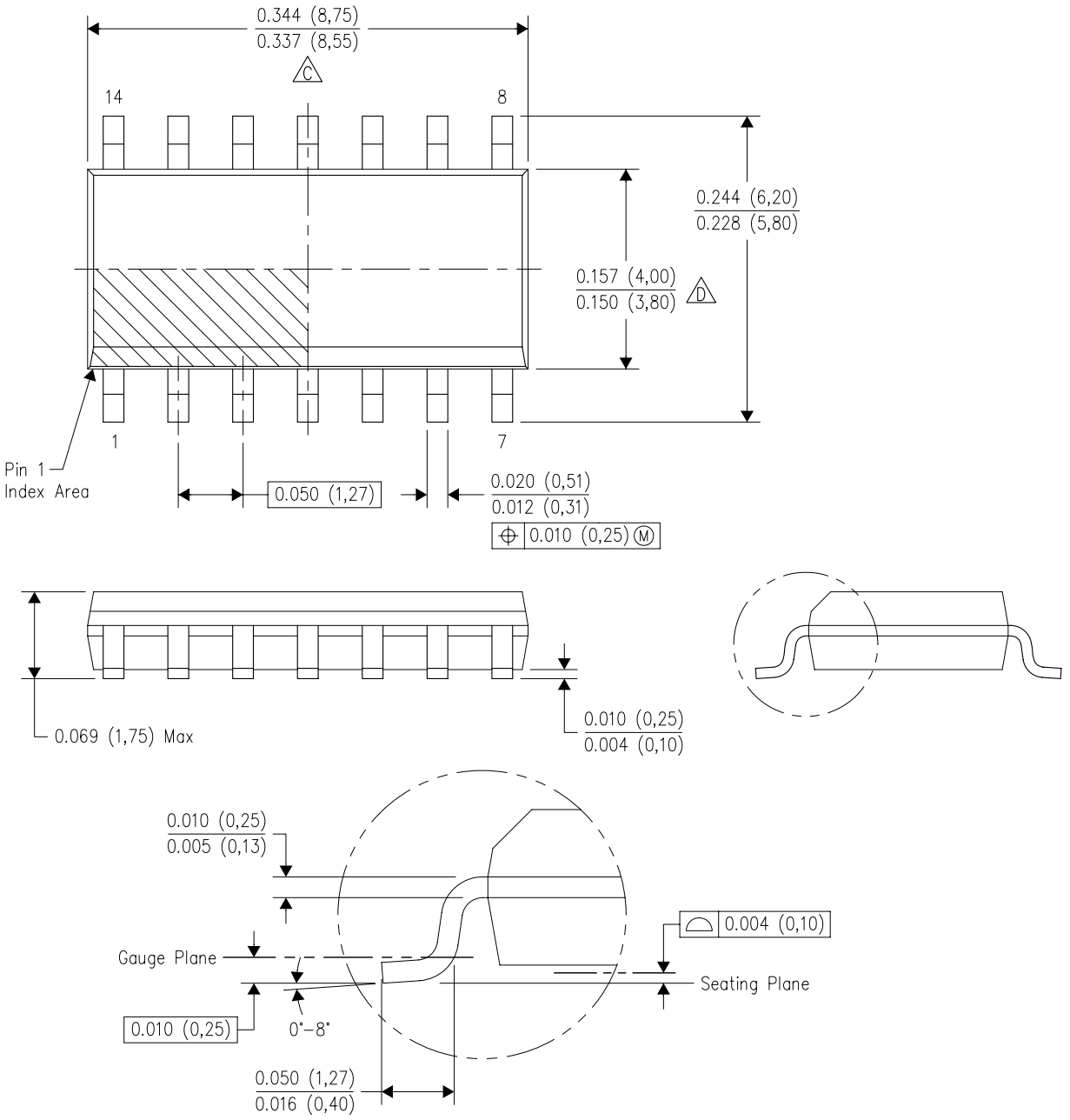
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA4364AQDRQ1	SOIC	D	14	2500	367.0	367.0	38.0

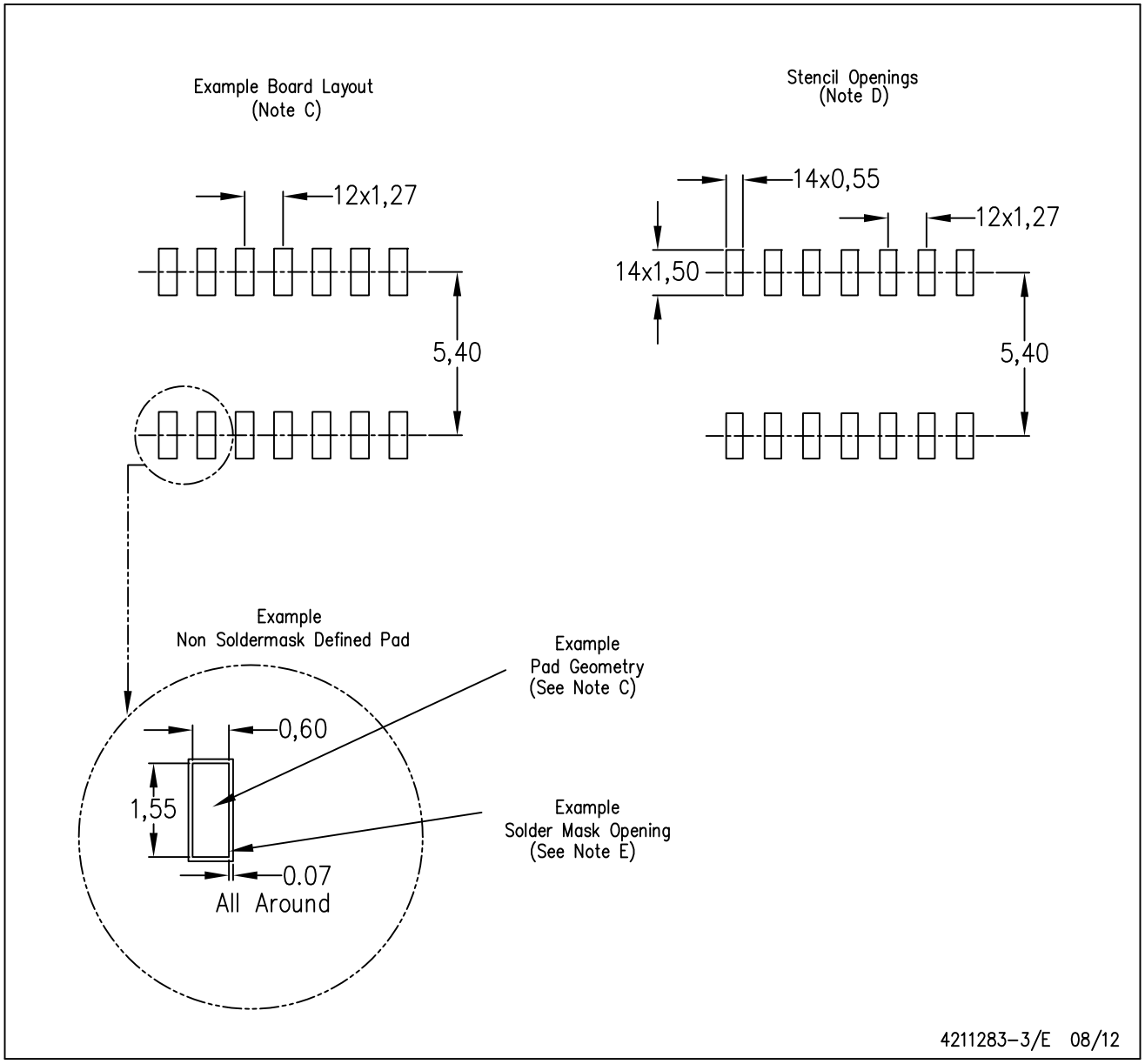
D (R–PDSO–G14) PLASTIC SMALL OUTLINE



4040047–5/M 06/11

NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AB.

D (R–PDSO–G14) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as “components”) are sold subject to TI’s terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI’s terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers’ products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers’ products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI’s goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or “enhanced plastic” are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have ***not*** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components which meet ISO/TS16949 requirements, mainly for automotive use. Components which have not been so designated are neither designed nor intended for automotive use; and TI will not be responsible for any failure of such components to meet such requirements.

Products		**Applications**	
Audio	www.ti.com/audio	Automotive and Transportation	www.ti.com/automotive
Amplifiers	amplifier.ti.com	Communications and Telecom	www.ti.com/communications
Data Converters	dataconverter.ti.com	Computers and Peripherals	www.ti.com/computers
DLP® Products	www.dlp.com	Consumer Electronics	www.ti.com/consumer-apps
DSP	dsp.ti.com	Energy and Lighting	www.ti.com/energy
Clocks and Timers	www.ti.com/clocks	Industrial	www.ti.com/industrial
Interface	interface.ti.com	Medical	www.ti.com/medical
Logic	logic.ti.com	Security	www.ti.com/security
Power Mgmt	power.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video
RFID	www.ti-rfid.com		
OMAP Applications Processors	www.ti.com/omap	**TI E2E Community**	e2e.ti.com
Wireless Connectivity	www.ti.com/wirelessconnectivity		

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2012, Texas Instruments Incorporated